ON Semiconductor

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Complementary Power Transistors

DPAK for Surface Mount Applications

Designed for general purpose power and switching such as output or driver stages in applications such as switching regulators, converters, and power amplifiers.

Features

- NJVMJD44H11 is NPN
- NJVMJD45H11 is PNP
- Lead Formed for Surface Mount Application in Plastic Sleeves (No Suffix)
- Electrically Similar to Popular D44H/D45H Series
- Low Collector Emitter Saturation Voltage
- Fast Switching Speeds
- Complementary Pairs Simplifies Designs
- Epoxy Meets UL 94 V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^{\circ}C$, common for NPN and PNP, minus sign, "–", for PNP omitted, unless otherwise noted)

Rating	Symbol	Max	Unit
Collector–Emitter Voltage	V_{CEO}	80	Vdc
Emitter-Base Voltage	V_{EB}	5	Vdc
Collector Current – Continuous	Ic	8	Adc
Collector Current – Peak	I _{CM}	16	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	20 0.16	W W/°C
Total Power Dissipation (Note 1) @ T _A = 25°C Derate above 25°C	P _D	1.75 0.014	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C
ESD – Human Body Model	HBM	3B	V
ESD – Machine Model	MM	С	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

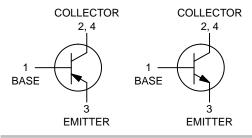


ON Semiconductor®

www.onsemi.com

SILICON POWER TRANSISTORS 8 AMPERES 80 VOLTS, 20 WATTS

COMPLEMENTARY





DPAK CASE 369C STYLE 1

MARKING DIAGRAM



A = Assembly Location

Y = Year WW = Work Week J4xH11 = Device Code x = 4 or 5

G

ORDERING INFORMATION

Pb-Free Package

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

These ratings are applicable when surface mounted on the minimum pad sizes recommended.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	6.25	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	71.4	°C/W
Lead Temperature for Soldering	TL	260	°C

^{2.} These ratings are applicable when surface mounted on the minimum pad sizes recommended.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C, common for NPN and PNP, minus sign, "-", for PNP omitted, unless otherwise noted)$

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•		•		
	V _{CEO(sus)}	80	-	-	Vdc
Collector Cutoff Current (V _{CE} = Rated V _{CEO} , V _{BE} = 0)	I _{CES}	-	-	1.0	μΑ
Emitter Cutoff Current (V _{EB} = 5 Vdc)	I _{EBO}	-	-	1.0	μΑ
ON CHARACTERISTICS					
Collector–Emitter Saturation Voltage (I _C = 8 Adc, I _B = 0.4 Adc)	V _{CE(sat)}	-	-	1	Vdc
Base–Emitter Saturation Voltage (I _C = 8 Adc, I _B = 0.8 Adc)	V _{BE(sat)}	-	-	1.5	Vdc
DC Current Gain (V _{CE} = 1 Vdc, I _C = 2 Adc) (V _{CE} = 1 Vdc, I _C = 4 Adc)	h _{FE}	60 40	- -	- -	-
DYNAMIC CHARACTERISTICS					_
Collector Capacitance (V _{CB} = 10 Vdc, f _{test} = 1 Mhz) MJD44H11 MJD45H11	C _{cb}	- -	45 130	- -	pF
Gain Bandwidth Product (I _C = 0.5 Adc, V _{CE} = 10 Vdc, f = 20 Mhz) MJD44H11 MJD45H11	f _T	- -	85 90	-	MHz
SWITCHING TIMES	-		-		<u>, </u>
Delay and Rise Times (I _C = 5 Adc, I _{B1} = 0.5 Adc) MJD44H11 MJD45H11	t _d + t _r	- -	300 135	- -	ns
Storage Time (I _C = 5 Adc, I _{B1} = I _{B2} = 0.5 Adc) MJD44H11 MJD45H11	t _s		500 500		ns
Fall Time (I _C = 5 Adc, I _{B1} = I _{B2} = 0.5 Adc) MJD44H11 MJD45H11	t _f	- -	140 100	<u>-</u>	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

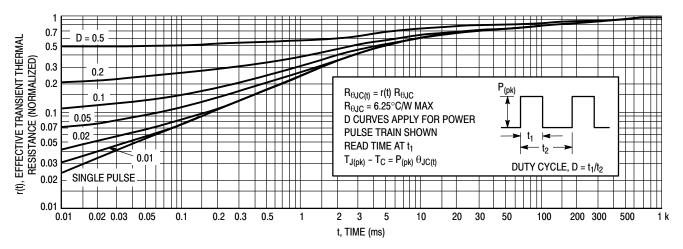


Figure 1. Thermal Response

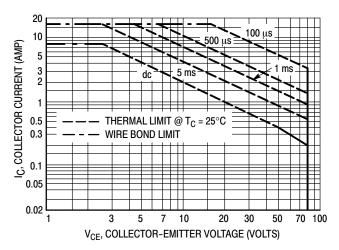


Figure 2. Maximum Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on $T_{J(pk)} = 150^{\circ}C$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 1. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

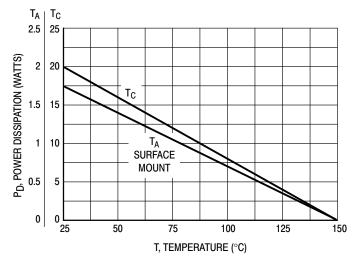


Figure 3. Power Derating

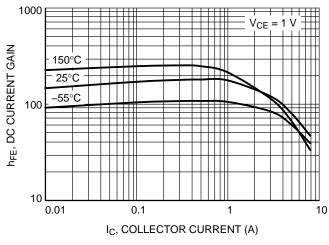


Figure 4. MJD44H11 DC Current Gain

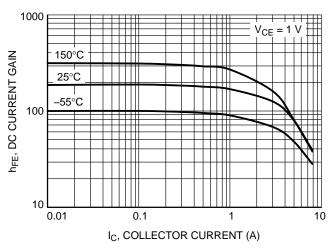


Figure 5. MJD45H11 DC Current Gain

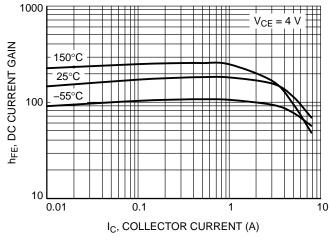


Figure 6. MJD44H11 DC Current Gain

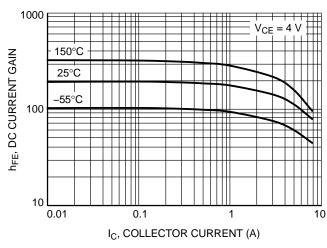


Figure 7. MJD45H11 DC Current Gain

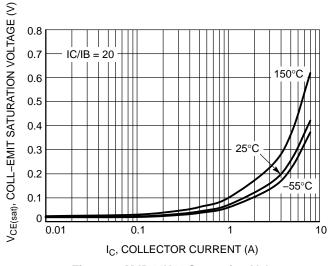


Figure 8. MJD44H11 Saturation Voltage $V_{CE(sat)}$

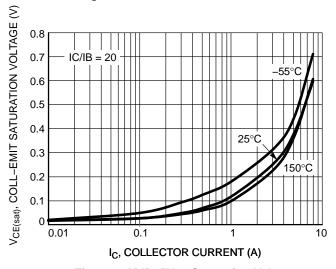


Figure 9. MJD45H11 Saturation Voltage $V_{CE(sat)}$

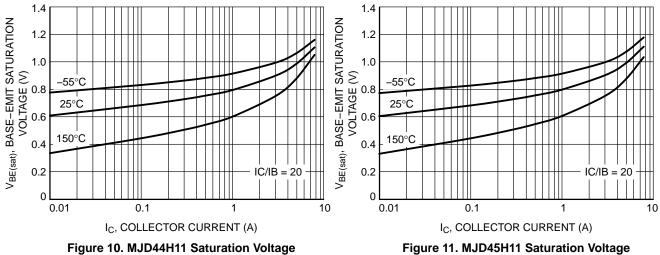
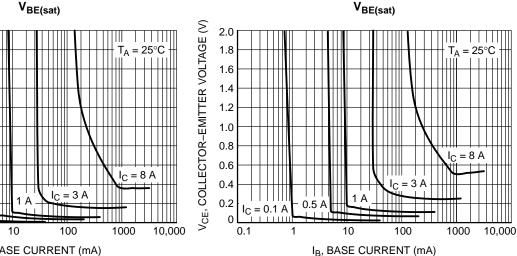


Figure 10. MJD44H11 Saturation Voltage V_{BE(sat)}

2.0



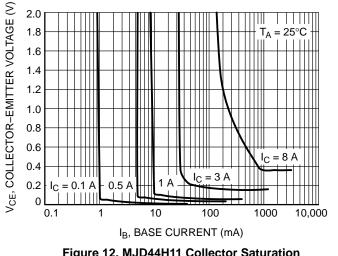




Figure 13. MJD45H11 Collector Saturation Region

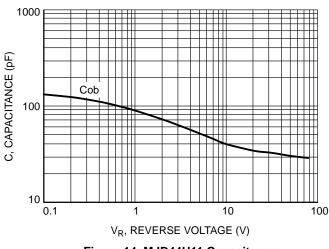


Figure 14. MJD44H11 Capacitance

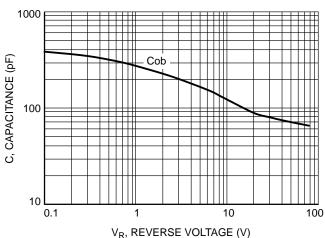


Figure 15. MJD45H11 Capacitance

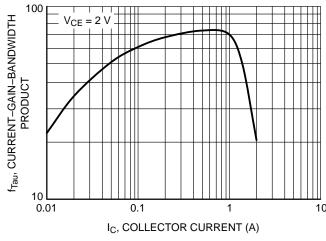


Figure 16. MJD44H11 Current-Gain-Bandwidth Product

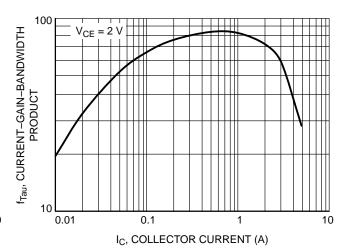


Figure 17. MJD45H11 Current-Gain-Bandwidth Product

ORDERING INFORMATION

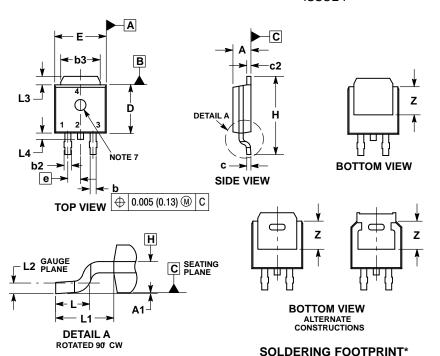
Device	Package Type	Shipping [†]	
NJVMJD44H11RLG-VF01*	DPAK (Pb-Free)	1,800 / Tape & Reel	
NJVMJD44H11T4G-VF01*	DPAK (Pb-Free)	2,500 / Tape & Reel	
NJVMJD45H11RLG-VF01*	DPAK (Pb-Free)	1,800 / Tape & Reel	
NJVMJD45H11T4G-VF01*	DPAK (Pb-Free)	2,500 / Tape & Reel	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable

PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE)

CASE 369C ISSUE F



NOTES

- 1. DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCHES.
- 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-MENSIONS b3, L3 and Z.
- WENSIONS DS, LS allO E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
- DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- 6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
- 7. OPTIONAL MOLD FEATURE.

	INCHES		MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.028	0.045	0.72	1.14
b3	0.180	0.215	4.57	5.46
С	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
е	0.090 BSC		2.29 BSC	
Н	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.114 REF		2.90 REF	
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Z	0.155		3.93	

STYLE 1:

- PIN 1. BASE 2. COLLECTOR
 - 3. EMITTER 4. COLLECTOR
- 6.20 3.00 0.244 0.118 2.58 0.102 5.80 1.60 6.17 0.228 0.063 0.243

SCALE 3:1

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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